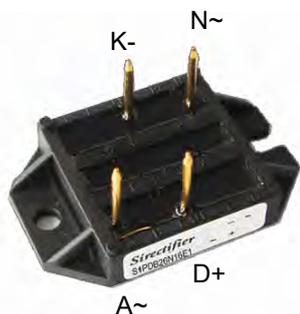


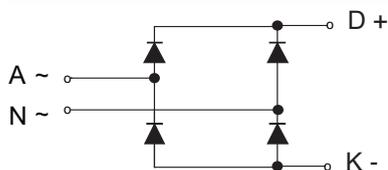
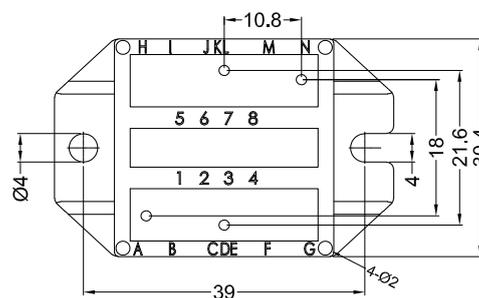
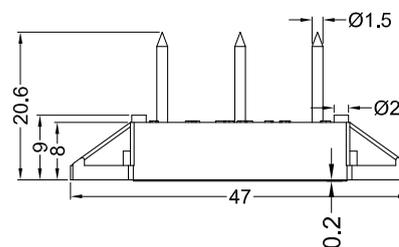
S1PDBF26N06E1

Single Phase Rectifier Bridge With FRED



Type	V _{RSM} V	V _{RSM} V
S1PDBF26N06E1	600	600

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I _{dav} I _{davm}	T _C =100°C, module T _A =45°C (R _{thCA} =0.6K/W), module	44 90	A
I _{FSM}	T _{VJ} =45°C V _R =0 t=10ms (50Hz), sine t=8.3ms (60Hz), sine	110 120	A
	T _{VJ} =T _{VJM} V _R =0 t=10ms(50Hz), sine t=8.3ms(60Hz), sine	95 105	
I ² t	T _{VJ} =45°C V _R =0 t=10ms (50Hz), sine t=8.3ms (60Hz), sine	60 60	A ² s
	T _{VJ} =T _{VJM} V _R =0 t=10ms(50Hz), sine t=8.3ms(60Hz), sine	45 45	
T _{VJ} T _{VJM} T _{stg}		-40...+150 150 -40...+150	°C
V _{ISOL}	50/60Hz, RMS I _{ISOL} ≤1mA t=1min t=1s	3000 3600	V~
M _d	Mounting torque (M4) Terminal connection torque (M4)	1.5-2.0 1.5-2.0	Nm
Weight	typ.	19	g

Sirectifier®

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Single Phase Rectifier Bridge With FRED

Symbol	Test Conditions	Characteristic Values		Unit
		Typ.	Max	
I_R	$V_R=V_{RRM}; T_{VJ}=25^{\circ}C$ $V_R=V_{RRM}; T_{VJ}=T_{VJM}$		0.1 0.5	mA
V_F	$I_F=15A; T_{VJ}=25^{\circ}C$		2.00	V
V_{FO}	For power-loss calculations only		1.13	V
r_F	$T_{VJ}=T_{VJM}$		13	mΩ
R_{thJC}	per diode per module		1.60 0.40	K/W
R_{thCH}	per diode per module		0.30 0.075	K/W
I_{RM}	$I_F = 25 A, -di_f/dt = 100 A/\mu s$ $V_R = 100 V, L = 0.05 mH, T_{VJ} = 100^{\circ}C$	4	4.9	A
t_{tr}	$I_F = 1 A; -di/dt = 100 A/\mu s; V_R = 30 V, T_{VJ} = 25^{\circ}C$	35		ns
d_s	Creeping distance on surface		11.20	mm
d_A	Creepage distance in air		9.7	mm
a	Max. allowable acceleration		50	m/s ²

FEATURES

- Package with DCB ceramic base plate in low profile
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

APPLICATIONS

- Supplies for DC power equipment
- Input and output rectifiers for high frequency
- Battery DC power supplies
- Field supply for DC motors

ADVANTAGES

- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight
- Low noise switching

S1PDBF26N06E1

Single Phase Rectifier Bridge With FRED

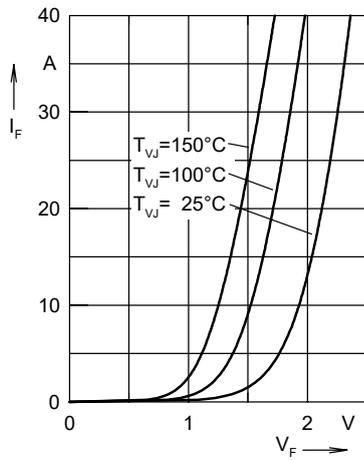


Fig. 1 Forward current I_F versus V_F

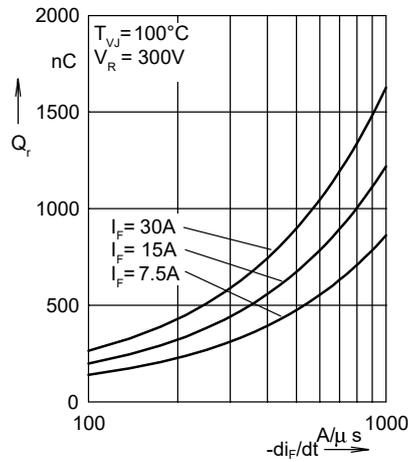


Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

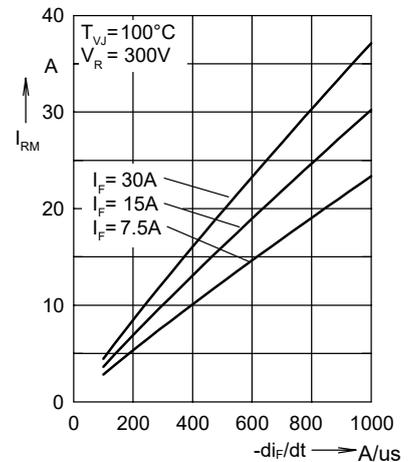


Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

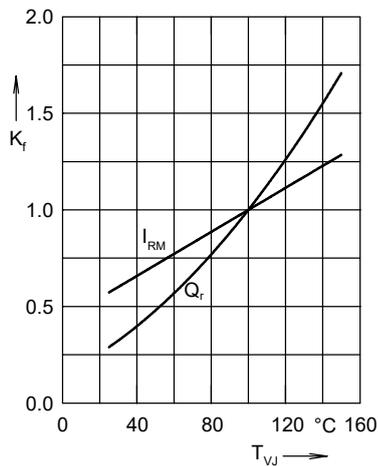


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

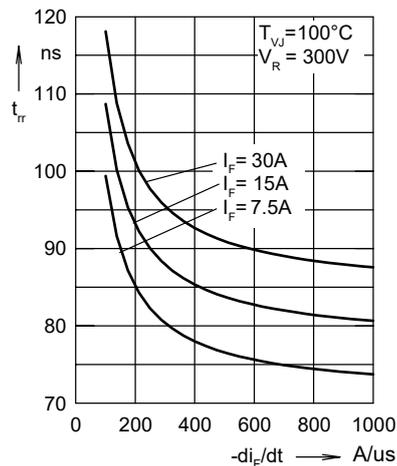


Fig. 5 Recovery time t_{tr} versus $-di_F/dt$

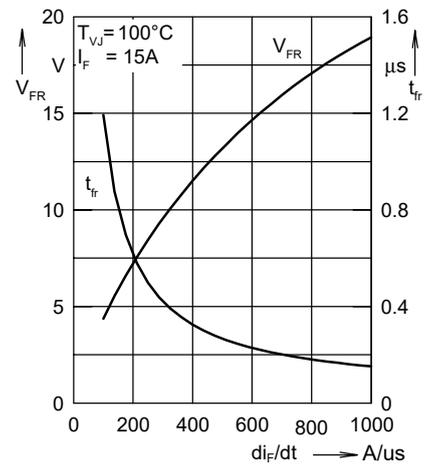


Fig. 6 Peak forward voltage V_{FR} and t_{tr} versus di_F/dt

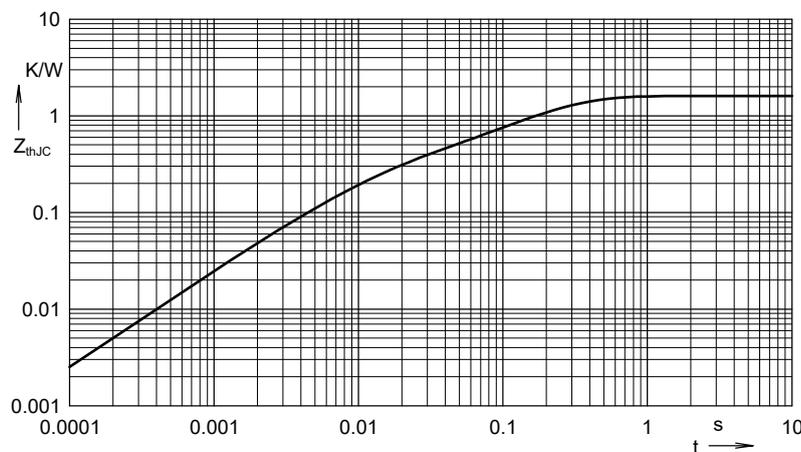


Fig. 7 Transient thermal resistance junction to case

Constants for Z_{thJC} calculation:

i	$R_{thi}(K/W)$	$t_i(s)$
1	0.5464	0.0052
2	0.2104	0.0003
3	0.0432	0.0004
4	0.8	0.0092